Student ID Number: Model Answer

Section:

Lecturer: Dr. Jamaludin Bin Omar

EEEB273 - Quiz 1

SEMESTER 2, ACADEMIC YEAR 2013/2014

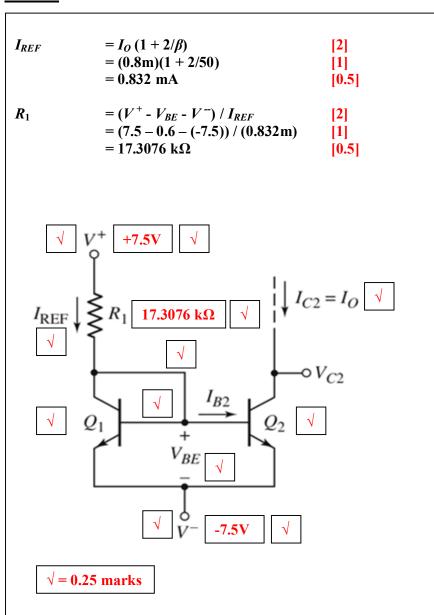
Date: 22 Oct 2013 Time: 15 minutes

## **Question:**

**DESIGN** a two-transistor BJT current source using NPN transistors so that **its output current** ( $I_0$ ) is **0.8 mA**. All transistors are matched. The transistor parameters are  $V_{BE}$  (**on**) = **0.6 V**,  $V_A = \infty$ , and  $\beta = 50$ . The circuit parameters are  $V^+ = 7.5$  V and  $V^- = -7.5$  V.

Draw the circuit diagram of your design. Show clearly all calculations as marks are given according to this.

[10 marks]



$$i_{C} = I_{S}e^{v_{BE}/V_{T}}$$
; npn
 $i_{C} = I_{S}e^{v_{EB}/V_{T}}$ ; ppp
 $i_{C} = \alpha i_{E} = \beta i_{B}$ 
 $i_{E} = i_{B} + i_{C}$ 

$$\alpha = \frac{\beta}{\beta + 1}$$
; Small signal
$$\beta = g_{m}r_{\pi}$$

$$r_{\pi} = \frac{\beta V_{T}}{I_{CQ}}$$

$$g_{m} = \frac{I_{CQ}}{V_{T}}$$

$$r_{o} = \frac{V_{A}}{I_{CQ}}$$

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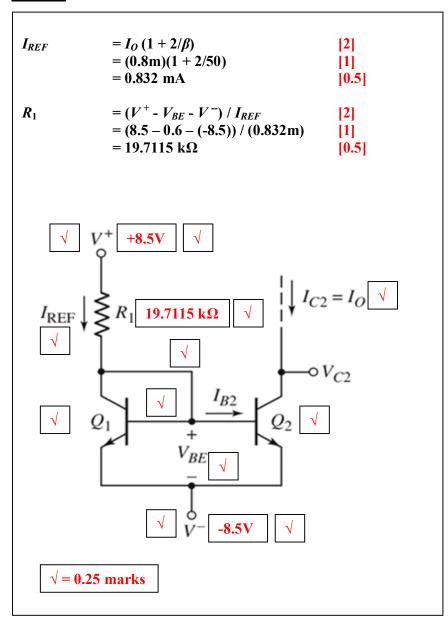
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# **Question:**

**DESIGN** a two-transistor BJT current source using NPN transistors so that **its output current** ( $I_0$ ) is **0.8 mA**. All transistors are matched. The transistor parameters are  $V_{BE}$  (**on**) = **0.6 V**,  $V_A = \infty$ , and  $\beta = 50$ . The circuit parameters are  $V^+ = 8.5$  V and  $V^- = -8.5$  V.

**Draw** the circuit diagram of your design. **Show clearly all calculations** as marks are given according to this.

[10 marks]



$$i_{C} = I_{S}e^{v_{BE}/V_{T}}$$
; npn
 $i_{C} = I_{S}e^{v_{EB}/V_{T}}$ ; pnp
 $i_{C} = \alpha i_{E} = \beta i_{B}$ 
 $i_{E} = i_{B} + i_{C}$ 

$$\alpha = \frac{\beta}{\beta + 1}$$
; Small signal
$$\beta = g_{m}r_{\pi}$$

$$r_{\pi} = \frac{\beta V_{T}}{I_{CQ}}$$

$$g_{m} = \frac{I_{CQ}}{V_{T}}$$

$$r_{o} = \frac{V_{A}}{I_{CQ}}$$

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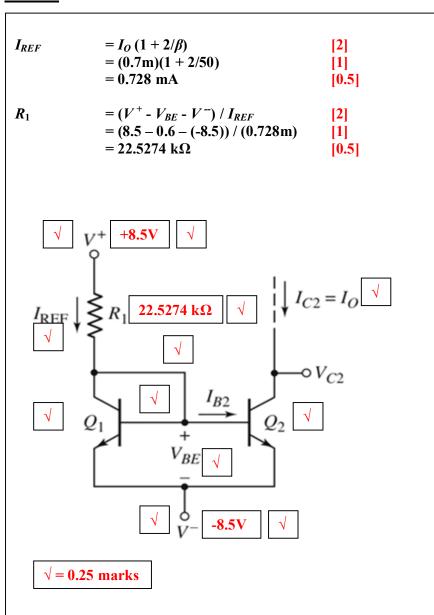
Date: 22 Oct 2013 Time: 15 minutes

# **Question:**

**DESIGN** a two-transistor BJT current source using NPN transistors so that **its output current** ( $I_0$ ) is **0.7 mA**. All transistors are matched. The transistor parameters are  $V_{BE}$  (**on**) = **0.6 V**,  $V_A = \infty$ , and  $\beta = 50$ . The circuit parameters are  $V^+ = 8.5$  V and  $V^- = -8.5$  V.

Draw the circuit diagram of your design. Show clearly all calculations as marks are given according to this.

[10 marks]



$$i_C = I_S e^{v_{BE}/V_T}$$
; npn
 $i_C = I_S e^{v_{EB}/V_T}$ ; ppp
 $i_C = \alpha i_E = \beta i_B$ 
 $i_E = i_B + i_C$ 
 $\alpha = \frac{\beta}{\beta + 1}$ 
; Small signal
 $\beta = g_m r_\pi$ 
 $\beta V_T$ 

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EEEB273 - Quiz 1

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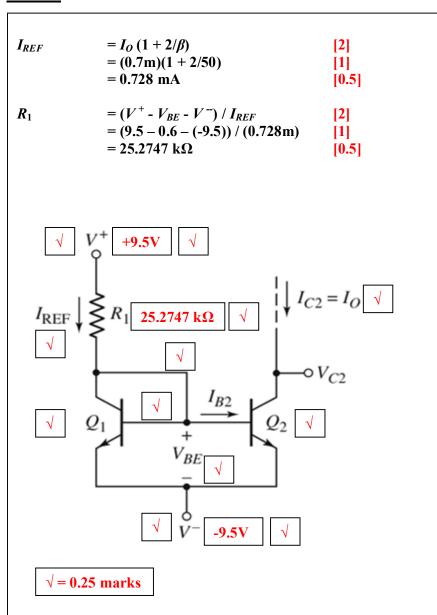
Date: 22 Oct 2013 Time: 15 minutes

# **Question:**

**DESIGN** a two-transistor BJT current source using NPN transistors so that **its output current** ( $I_0$ ) is **0.7 mA**. All transistors are matched. The transistor parameters are  $V_{BE}$  (**on**) = **0.6 V**,  $V_A = \infty$ , and  $\beta = 50$ . The circuit parameters are  $V^+ = 9.5$  V and  $V^- = -9.5$  V.

Draw the circuit diagram of your design. Show clearly all calculations as marks are given according to this.

[10 marks]



$$i_{C} = I_{S}e^{v_{BE}/V_{T}}; \text{npn}$$

$$i_{C} = I_{S}e^{v_{EB}/V_{T}}; \text{pnp}$$

$$i_{C} = \alpha i_{E} = \beta i_{B}$$

$$i_{E} = i_{B} + i_{C}$$

$$\alpha = \frac{\beta}{\beta + 1}$$
;Small signal
$$\beta = g_{m}r_{\pi}$$

$$r_{\pi} = \frac{\beta V_{T}}{I_{CQ}}$$

$$g_{m} = \frac{I_{CQ}}{V_{T}}$$

$$r_{o} = \frac{V_{A}}{I_{CQ}}$$